NSN 5961-00-307-9856

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-307-9856 **Inclosure Material:** Ceramic **Overall Length:** Between 0.205 inches and 0.225 inches **Overall Diameter:** 0.125 inches **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 breakdown voltage, dc and 60.0 breakdown voltage, dc **Power Rating Per Characteristic:** 5.0 watts large-signal input power, common-emitter preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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